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journal homepage: www.elsevier.com/locate/jmmmSpin-polarization in filled-skutterudites $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb)A.H. Reshak ^{a,b,*}^a New Technologies–Research Centre, University of West Bohemia, Univerzitni 8, 306 14 Pilsen, Czech Republic^b Center of Excellence Geopolymer and Green Technology, School of Material Engineering, University Malaysia Perlis, 01007 Kangar, Perlis, Malaysia

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ABSTRACT

We have performed spin-polarized calculation for the electronic band structure, density of states, Fermi surface and the space electronic charge density distribution for the filled-skutterudites $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb) compounds. It has been noticed that for both $\text{LaFe}_4\text{P}_{12}$ and $\text{LaFe}_4\text{As}_{12}$ there are two bands cross Fermi level (E_F) for the spin-up and spin-down states, while for $\text{LaFe}_4\text{Sb}_{12}$ there is only one band cross E_F for the spin-up state and three bands cross E_F for the spin-down state. As the partial DOS of La-s, d, Fe-s/p/d and Pn-s/p/d coincide Fermi level at nonzero value, it reveals that the electrons of these orbitals contribute in the conduction process. The calculated values of the density of the states at Fermi level $N(E_F)$ and the associated electronic specific heat coefficient (γ) for the spin-up/down states are decreases with substituting $\text{P} \rightarrow \text{As} \rightarrow \text{Sb}$. The bonds nature and the interactions between the atoms for the spin-up/down configurations were investigated in (1 0 0) and (1 0 1) crystallographic planes.

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1. Introduction

Due to their interesting physical and chemical properties, the filled skutterudite compounds have attracted much attention as potential candidates. It has been demonstrated that the filled skutterudite compounds are promising materials for electrical, magnetic and thermoelectric applications [1] due to their high carrier mobility, low lattice thermal conductivity and low electrical resistivity [1–3]. Much more interesting phenomena have been observed in the filled skutterudite compounds, for instance semiconductivity [4,5], superconductivity [6–8], magnetic order [9–13], metal-insulator transition material [14] and valence fluctuation and heavy fermion behavior [15–17]. Moreover, the filled skutterudite compounds $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb) exhibit phonon-glass electron-crystals which make these compounds as promising materials for thermoelectric applications [18–20]. The La-based filled skutterudite phosphide, arsenide and antimonide [21,22] are very important members of the filled skutterudite compounds. Therefore, several researchers have performed experimental and theoretical investigation on this group in order to understand the functionality of these materials. Recently Pulikkotil

et al. [20] have performed first-principles calculations within local density approximation (LDA) to clarify the influence of FeSb_6 octahedral deformations on the structural and electronic structure properties of $\text{LaFe}_4\text{Sb}_{12}$. It has been found that octahedral tilting correlate with the band dispersions and hence the band masses [20].

The band structure and Fermi surface of $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb) compounds were investigated theoretically within the density functional theory [23]. Furthermore, using the full potential linear augmented plane wave (FPLAPW) method within the local density approximation (LDA), Takegahara and Harima [24] investigated the band structure of simple cubic $\text{LaRu}_4\text{P}_{12}$ and the orthorhombic $\text{LaFe}_4\text{P}_{12}$ compounds. The Fermi surface and the hybridization between La-f orbital and P-p states were also investigated. An *ab initio* calculation using LDA to investigate the structural and elastic properties of $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb) compounds were reported by Hachemaoui et al. [25]. The density of states near Fermi level and the corresponding thermoelectric properties of $\text{LaFe}_4\text{Sb}_{12}$ and $\text{CeFe}_4\text{Sb}_{12}$ compounds were investigated using tight-binding linear muffin-tin orbital (TB-LMTO) and full potential linear augmented plane wave (FPLAPW) methods [26].

From above it is clear that there exists a number of band structure calculations for $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn} = \text{P}, \text{As}$ and Sb) compounds using different methods within local density approximation (LDA) and generalized gradient approximation (GGA) as exchange and

* Corresponding author at: New Technologies–Research Centre, University of West Bohemia, Univerzitni 8, 306 14 Pilsen, Czech Republic.

E-mail address: maalidph@yahoo.co.uk

correlation potentials. It is well known that for the highly correlated compounds, LDA and GGA are known to fail to give the correct ground state. In these systems, the electrons are highly localized. The Coulomb repulsion between the electrons in open shells should be taken into account [27]. Therefore, this motivates us to address ourselves for a comprehensive theoretical calculation using the all-electron full potential linear augmented plane wave plus the local orbitals (FP-LAPW+lo) method within the recently modified Becke–Johnson potential (mBJ) [28], to investigate the influence of substituting P→As→Sb on the electronic band structure, density of states, Fermi surface and the electronic charge distributions. The modified Becke–Johnson potential allows the calculation with accuracy similar to the very expensive GW calculations [28]. It is a local approximation to an atomic “exact-exchange” potential and a screening term. To the best of our knowledge there is dearth of spin polarizing calculation for the $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) compounds therefore, we have calculated the spin polarized electronic band structure, electronic charge distribution, total and the angular momentum resolved projected density of states and Fermi surface of these compounds meanwhile we have investigated the influence of substituting P→As→Sb on these properties in the presence of the spin polarization. The FP-LAPW+lo method has proven to be one of the accurate methods for the computation of the electronic structure of solids within density functional theory (DFT) [29–33].

2. Details of calculations

The electronic and magnetic properties of the filled-skutterudites $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) compounds are calculated using the all-electron full potential linear augmented plane wave plus local orbitals (FP-LAPW+lo) method accomplished by using the WIEN2k code [34]. It is well known that the electronic properties of any compound are strongly depend on the configuration of the electronic structure, thus it is essential to investigate the electronic structure. $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) compounds crystallized in cubic structure, the space group is $\text{Im}\bar{3}$. In the unit cell, La atom is situated at 2a (0.0, 0.0, 0.0), Fe at 8c (0.25, 0.25, 0.25) and X at 24g (0.0, u , v) [21,22]. The lattice constant a and the two internal free parameters u and v were optimized by minimizing the total energy. The optimization is achieved using the local density approximation (LDA) [35]. These values are listed in Table 1 along with the bulk modulus B in (GPa) and its pressure derivative B' , in comparison with the experimental data and the previous results [22,23,25,36–38]. In order to achieve energy eigenvalues convergence, the wave functions in the interstitial region are expanded in terms of plane waves with a cut-off of $K_{\text{MAX}}=8/R_{\text{MT}}$. Self-consistency was achieved using 800 \vec{k} points in the irreducible Brillouin zone (IBZ). The spin-polarized electronic band structure and the related properties were calculated within 5000 \vec{k} points in IBZ using the recently modified Becke–Johnson potential (mBJ) [28]. The self-consistent calculations were converged since the total energy of the system was stable within 10^{-5} Ry.

3. Results and discussion

3.1. Spin polarized electronic band structure and density of states

Using mBJ approach the electronic band structure of $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) compounds are obtained for spin-up and spin-down electrons as shown in Fig. 1(a)–(f). We set the zero-point of energy at Fermi level (E_F). It has been found that the spin-polarization show significant influence on the bands dispersion. Also

Table 1

The calculated lattice constant, the free internal parameters u and v and the bulk modulus B in (GPa) and its pressure derivative B' of $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) in comparison with the experimental data and the previous theoretical results.

	$\text{LaFe}_4\text{P}_{12}$	$\text{LaFe}_4\text{As}_{12}$	$\text{LaFe}_4\text{Sb}_{12}$
a (Å)	7.8315*	8.3251*	9.1392*
	7.724 ^a	8.179 ^a	8.963 ^a
	7.8316 ^b (Exp.)	8.3252 ^c (Exp.)	9.1392 ^d (Exp.)
	7.8217 ^f	8.3252 ^f	9.1487 ^e (Exp.)
u	0.3530*	0.3453*	0.3365*
	0.3527 ^a	0.3418 ^a	0.3344 ^a
	0.3539 ^b (Exp.)	0.34556 ^c (Exp.)	0.33696 ^d (Exp.)
v	0.1511*	0.15521*	0.1610*
	0.1543 ^a	0.15667 ^a	0.1612 ^a
	0.1504 ^b (Exp.)	0.15474 ^c (Exp.)	0.16042 ^d (Exp.)
B	160.2*	145.7*	104.5*
	177.11 ^a	152.09 ^a	115.82 ^a
B'			88.9 ^e (Exp.)
	3.60*	3.1*	101.4 ^f (calc.)
	4.21 ^a	4.03 ^a	2.98*
			3.49 ^a

^a Ref. [25]

^b Ref. [22]

^c Ref. [36]

^d Ref. [37]

^e Ref. [38]

^f Ref. [23]

moving from P to As to Sb cause significant influence on the bands dispersion mainly the dispersionless bands below E_F which show large peak at E_F in the density of states as illustrated in Figs. 2(a), 3 (a) and 4(a). That is attributed to the fact that moving from P→As→Sb lead to increase the interatomic distances which cause to push up electronic energies on the neighboring atoms. Also it has been noticed that for both of $\text{LaFe}_4\text{P}_{12}$ and $\text{LaFe}_4\text{As}_{12}$ there are two bands cut E_F for the spin-up and spin-down cases, while for $\text{LaFe}_4\text{Sb}_{12}$ there is only one band cuts E_F for the spin-up case and three bands cut E_F for the spin-down case. To confirm the influence of substituting P→As→Sb on the spin-up/down configurations in the electron structure, we have calculated the spin-up and spin-down total and partial density of states as shown in Figs. 2–4. We would like to mention that the density of states exhibits the distribution of the electronic state as a function of energy. The area under each curve for each individual energy interval equals to the number of allowed electronic states in the particular interval. The spin polarization cause to reduce the value of the density of states at Fermi level $N(E_F)$ when we move from P→As→Sb for both spin-up and spin-down. Also a clear reduction can be seen in the associated electronic specific heat coefficient (γ) which can be determined by using the expression $\gamma = \frac{1}{3}\pi^2 N(E_F) k_B^2$, where k_B is the Boltzmann constant. The calculated values of $N(E_F)$ and γ for $\text{LaFe}_4\text{Pn}_{12}$ ($\text{Pn}=\text{P}$, As and Sb) compounds are listed in Table 2. We should emphasize that the electro-negativity of P, As and Sb atoms are 2.19, 2.18 and 2.05, respectively according to the Pauling scale. Therefore, due to the small electro-negativity differences between P, As and Sb, no more peaks will be introduced in the density of states when we move from P→As→Sb. The desperation of the PDOS helps to identify the angular momentum characters of the various structures. It is clear that La-s, Fe-s/p and Pn-s/p states are contributing along the whole energy range for both spin-up and spin-down configurations. While the contribution of Fe-d state is confined in two regions (−6.0 upto E_F) eV and (0.1 and above), La-d contribute from 1.5 eV and above whereas La-f concentrated around 3.0 eV, and L-d exhibit main contribution above E_F . It is clear that in $\text{LaFe}_4\text{P}_{12}$ compound the La-p state shows very shape rise around −16.5 eV for spin-up/down states, a significant reduction occurs in La-p state for the spin-down state when we

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